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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/038,125	01/02/2002	Geon Choe	SJO920010040US1	7458
759	90 10/14/2004		EXAM	INER
David W. Lynch			OMETZ, DAVID LOUIS	
Crawford & Maunu PLLC 1270 Northland Drive		ART UNIT	PAPER NUMBER	
Suite 390			2653	
Mendota Heights, MN 55120			DATE MAILED: 10/14/2004	

Please find below and/or attached an Office communication concerning this application or proceeding.

	Application No.	Applicant(s)				
	10/038,125	CHOE, GEON				
Office Action Summary	Examiner	Art Unit				
	David L. Ometz	2653				
The MAILING DATE of this communication a Period for Reply	appears on the cover sheet v	vith the correspondence ac	idress			
A SHORTENED STATUTORY PERIOD FOR REF THE MAILING DATE OF THIS COMMUNICATION - Extensions of time may be available under the provisions of 37 CFR after SIX (6) MONTHS from the mailing date of this communication. - If the period for reply specified above is less than thirty (30) days, a - If NO period for reply is specified above, the maximum statutory peri - Failure to reply within the set or extended period for reply will, by state Any reply received by the Office later than three months after the may be earned patent term adjustment. See 37 CFR 1.704(b).	N. 1.136(a). In no event, however, may a reply within the statutory minimum of the field will apply and will expire SIX (6) MC attue, cause the application to become A	reply be timely filed irty (30) days will be considered time INTHS from the mailing date of this of ABANDONED (35 U.S.C. § 133).	ly. communication.			
Status						
1) Responsive to communication(s) filed on 23	3 August 2004.					
,	☐ This action is FINAL . 2b) ☑ This action is non-final.					
3) Since this application is in condition for allow			e merits is			
closed in accordance with the practice unde	er <i>Ex parte</i> Q <i>uayle</i> , 1935 C.	D. 11, 453 O.G. 213.				
Disposition of Claims						
4)⊠ Claim(s) <u>1-9,12 and 13</u> is/are pending in the	4)⊠ Claim(s) <u>1-9,12 and 13</u> is/are pending in the application.					
4a) Of the above claim(s) is/are without	drawn from consideration.					
5) Claim(s) is/are allowed.						
6)⊠ Claim(s) <u>1,3-9,12 and 13</u> is/are rejected.	3)⊠ Claim(s) <u>1,3-9,12 and 13</u> is/are rejected.					
• • • • • •	7) Claim(s) <u>2</u> is/are objected to.					
8) Claim(s) are subject to restriction an	a/or election requirement.	·				
Application Papers	-					
9)☐ The specification is objected to by the Examiner.						
10) The drawing(s) filed on is/are: a) accepted or b) objected to by the Examiner. ∕						
Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).						
Replacement drawing sheet(s) including the correction is required if the drawing(s) is objected to. See 37 CFR 1.121(d). 11) The oath or declaration is objected to by the Examiner. Note the attached Office Action or form PTO-152.						
Priority under 35 U.S.C. § 119		• +				
12) ☐ Acknowledgment is made of a claim for fore a) ☐ All b) ☐ Some * c) ☐ None of: 1. ☐ Certified copies of the priority docum 2. ☐ Certified copies of the priority docum 3. ☐ Copies of the certified copies of the papplication from the International But * See the attached detailed Office action for a	nents have been received. The nents have been received in priority documents have been reau (PCT Rule 17.2(a)).	Application No en received in this Nationa	ıl Stage			
Attachment(s)						
1) Notice of References Cited (PTO-892) 4) Interview Summary (PTO-413)						
 2) Notice of Draftsperson's Patent Drawing Review (PTO-948) 3) Information Disclosure Statement(s) (PTO-1449 or PTO/SB Paper No(s)/Mail Date 		o(s)/Mail Date f Informal Patent Application (PT 	ГО-152)			

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1. A request for continued examination under 37 CFR 1.114, including the fee set forth in 37 CFR 1.17(e), was filed in this application after final rejection. Since this application is eligible for continued examination under 37 CFR 1.114, and the fee set forth in 37 CFR 1.17(e) has been timely paid, the finality of the previous Office action has been withdrawn pursuant to 37 CFR 1.114. Applicant's submission filed on 8/23/04 has been entered.

- 2. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
 - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 3. Claims 1, 3-9, 12, 13 are rejected under 35 U.S.C. 103(a) as being unpatentable over JP 10-256621 in view of Journal of Applied Physics article "Oxygen as a surfactant in the Growth of Giant Magnetoresistive Spin Valves" to Egelhoff et al (hereinafter "Egelhoff"). JP '621 shows a method for providing precise control of magnetic coupling field in NiMn top spin valve head (see col. 2, lines 37-39 for permissible antiferromagnetic materials, specifically "NiMn" with a thickness of between "5-25nm"), comprising: forming at least one copper layer (3 or 5) in a NiMn top spin valve; and depositing remaining layers (free layer 4, pined layer 6, and antiferromagnetic layer 7) of the NiMn top spin valve head. However, JP'621 does not show the copper seed 3 and the copper spacer layer 5 being partly oxidized with oxygen. Egelhoff disclosed a spin valve head that oxidizes the copper spacer layer to greatly enhance the magnetoresisitive effect (see pages 6144-6147). Therefore, it would have been obvious to one of ordinary skill in the art at the time the invention was made to oxidize the copper layers in the spin valve of JP'621 as taught by Egelhoff as doing this would enhance the GMR effect over that

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of a non-oxidized spin valve head, and would increase the beneficial specular reflection of electrons by creating a smoother or more well ordered growth pattern of the layers as taught by Egelhoff. It is noted that with regard to the dependent claims 3, 4, 6, 7, 12, and 13 the various gains in the spin valve performance (e.g. claim 3-- reduces the ferromagnetic coupling field without deteriorating GMR effect or resistance; claim 4-- provides a negative coupling field without affecting GMR effect or resistance;; claim 7-- provides stronger growth of NiFe(111) and NiMn(111) with respect to NiFe(200) and NiMn(002) phases; claim 12--provides an approximately 15% increase in amplitude of the output of a NiMn spin valve head at the same coupling field; claim 13-- does not affect asymmetry performance) would all be inherent in oxidizing the copper layers in the JP'621 reference as the structure is the same as Applicant's NiMn top spin valve.

- 4. Claim 2 is objected to as being dependent upon a rejected base claim, but would be allowable if rewritten in independent form including all of the limitations of the base claim and any intervening claims.
- 5. Applicant's arguments filed 8/23/04 have been fully considered but they are not persuasive. Applicant asserts on page 5 that neither Takuji nor Egelhoff suggest an NiMn top spin valve head having an NiMn pinning layer with a thickness of less than 200 Angstroms. However, the examiner maintains that Takuji teaches in col. 2, line 39 that the thickness range of the NiMn pinning layer may lie between 5-25nm, which converts to 50-250 Angstroms, thus meeting the claimed limitation of less than 200 Anstroms.

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6. The prior art made of record and not relied upon is considered pertinent to applicant's disclosure. Carey et al teaches the oxidation of gap layers in a magnetoresistive head while Kula et al teaches oxidation of the copper spacer in a spin valve magnetoresistive head.

Any inquiry concerning this communication or earlier communications from the examiner should be directed to David L. Ometz whose telephone number is (703) 308-1296. The examiner can normally be reached on M-W, 6:00-4:00.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, William Korzuch can be reached on (703) 305-6137. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

David L. Ometz Primary Examiner

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DLO 10/13/04